

Model RFP-10N50T



Aluminum Nitride Terminations 10 Watts, 50 Ω



Features

- DC 6.0 GHz
- 10 Watts
- Aluminum Nitride (AIN) Ceramic
- Welded Silver Leads
- Non-Nichrome Resistive Element
- Low VSWR
- 100% Tested

General Specifications

Resistive Element: Thick film

Substrate: Aluminum nitride ceramic

Cover: Alumina ceramic

99.99% pure silver (.005" thk) Lead(s):

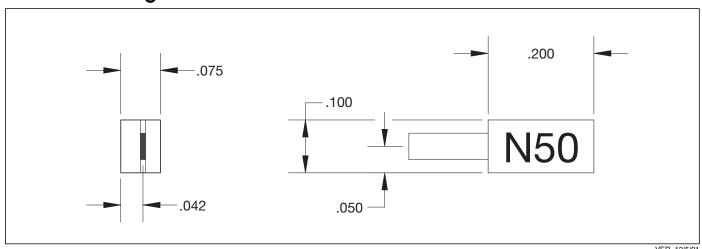
Electrical Specifications

Resistance Value: 50 ohms, ±5% DC - 6.0 GHz Frequency Range: Power: 10 Watts V.S.W.R.: 1.25:1

Notes: Tolerance is ±.010, unless otherwise specified. Operating temperature is -55°C to +150°C (see chart). Designed to meet or exceed applicable portions of MIL-E-5400. All dimensions are in inches. Lead length 0.15" minimum.

Specifications subject to change without notice.

Outline Drawing





Available on Tape and Reel for Pick and Place Manufacturing.

Sales Desk USA: Voice: (800) 544-2414 Fax: (315) 432-9121 Sales Desk Europe: Voice: (+44) 23 92 232392 Fax: (+44) 23 92 251369

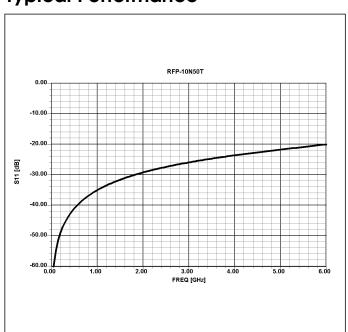


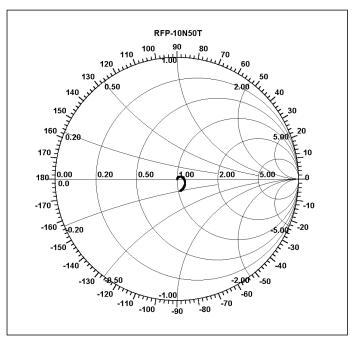
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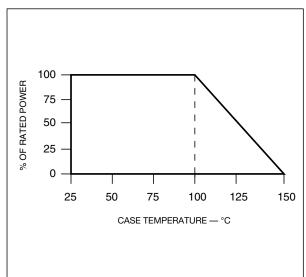


Typical Performance

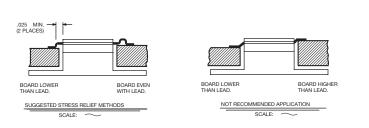




Power Derating



Suggested Mounting Procedures



- 1. Make sure that the devices are mounted on flat surfaces (.001" under the device) to optimize the heat transfer.
- 2. Position device on mounting surface and solder in place using an SN96 type solder.
- 3. Solder leads in place using an SN63 type solder with a controlled temperature iron (700°F).



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